TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC251AP,TC74HC251AF

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8-Channel Multiplexer (3-state)
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The TC74HC251A is a high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

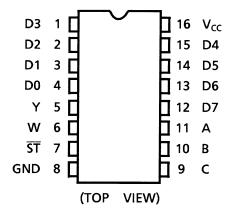
One of eight date input signals (D0-D7) is selected by decoding of the address input (A, B, C). The selected data appears on two outputs; non-inverting (Y) and inverting (W). When the strobe input is held high, both outputs are in the high-impedance state.

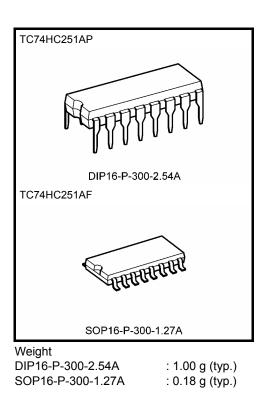
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 15 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS251

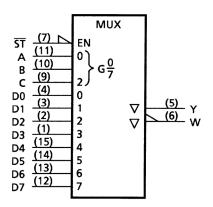
Pin Assignment





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IEC Logic Symbol



Truth Table

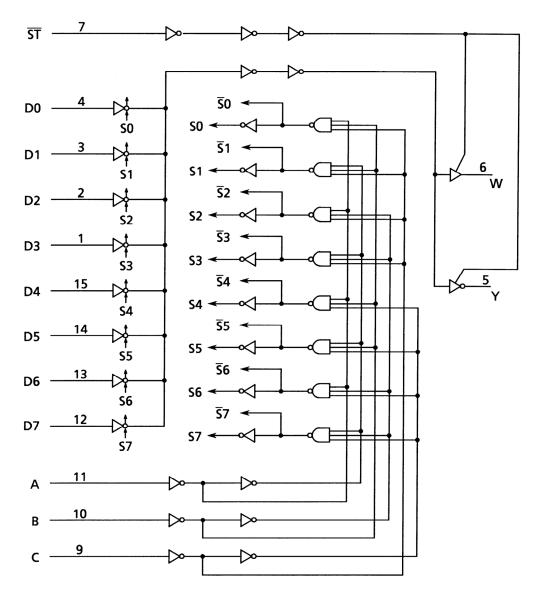
	h	Outputs			
Select			Strobe	v	w
С	В	А	ST	Y	vv
Х	Х	Х	Н	Z	Z
L	L	L	L	D0	D0
L	L	н	L	D1	D1
L	н	L	L	D2	D2
L	н	н	L	D3	D3
н	L	L	L	D4	D4
н	L	н	L	D5	D5
н	н	L	L	D6	D6
н	Н	Н	L	D7	D7

X: Don't care

H: High impedance

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System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7	V	
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V	
Input diode current	I _{IK}	±20	mA	
Output diode current	IOK	±20	mA	
DC output current	IOUT	±25	mA	
DC V _{CC} /ground current	ICC	±50	mA	
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW	
Storage temperature	T _{stg}	-65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40 \sim 65^{\circ}$ C. From Ta = 65 to 85° C a derating factor of -10 mW/°C shall be applied until 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	$0 \sim 500 (V_{CC} = 4.5 V)$	ns
		0~400 (V _{CC} = 6.0 V)	

Operating Ranges (Note)

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

		Test Condition		Ta = 25°C			Ta = −40~85°C				
Characteristics Symbol				V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
High-level input voltage	VIH	—		2.0	1.50	_	_	1.50	_		
				4.5	3.15	—	—	3.15	—	V	
				6.0	4.20	—	—	4.20			
					—	—	0.50	—	0.50		
Low-level input voltage	VIL	_		4.5	—		1.35	—	1.35	V	
Ĵ				6.0	_		1.80	—	1.80		
	V _{OH}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	—	1.9	—		
High-level output voltage			I _{OH} = -20 μA	4.5	4.4	4.5	—	4.4	—		
				6.0	5.9	6.0	—	5.9		V	
			I _{OH} = -4 mA	4.5	4.18	4.31	—	4.13	—		
			I _{OH} = -5.2 mA	6.0	5.68	5.80	—	5.63	—		
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 20 \ \mu A$	2.0	_	0.0	0.1	_	0.1		
				4.5	—	0.0	0.1	—	0.1		
Low-level output voltage				6.0	_	0.0	0.1	—	0.1	V	
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33		
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	—	0.33	l	
3-state off leak current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		6.0		_	±0.5	_	±5.0	μΑ	
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0		_	±0.1	_	±1.0	μΑ	
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		6.0			4.0		40.0	μΑ	

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Тур.	Max	Unit
Output transition time	t _{TLH}			4	8	ns
	t _{THL}					113
Propagation delay time	t _{pLH}			14	24	20
(D-Y)	t _{pHL}	—		14	24	ns
Propagation delay time	t _{pLH}		_	15	24	20
(D-W)	t _{pHL}					ns
Propagation delay time	t _{pLH}		—	19	31	ns
(A, B, C-Y)	t _{pHL}					115
Propagation delay time	t _{pLH}	—		19	31	
(A, B, C-W)	t _{pHL}					ns
3-state output enable time	t _{pZL}			10	18	20
	t _{pZH}	_		10	18	ns

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Ta = 25°C Ta = -40~85°C **Test Condition** Characteristics Symbol Unit Vcc Min Тур. Max Min Max (V) 2.0 30 75 95 ____ ____ t_{TLH} Output transition time 4.5 8 15 19 ns ____ ____ **t**THL 7 6.0 13 16 2.0 65 140 175 Propagation delay ____ ____ tpLH time 4.5 17 28 35 ns ____ ____ tpHL (D-Y) 6.0 14 24 30 ____ ____ 2.0 70 140 175 Propagation delay tpLH time 4.5 18 28 35 ns ____ ____ tpHL (D-W) 6.0 15 24 30 ____ _ 2.0 80 180 225 Propagation delay t_{pLH} time 4.5 23 36 45 ns ____ ____ tpHL (A, B, C-Y) 6.0 ____ 19 31 ____ 38 2.0 80 180 225 ____ Propagation delay t_{pLH} time 4.5 23 36 45 ns ____ tpHL (A, B, C-W) 6.0 19 31 38 ____ ____ 2.0 40 105 130 3-state output enable tpZL 4.5 13 21 26 ns ____ time t_{pZH} 6.0 10 19 22 2.0 25 105 130 ____ ____ tpLZ 3-state output disable 26 4.5 13 21 ns ____ ____ time t_{pHZ} 6.0 11 19 22 Input capacitance 5 10 10 CIN ____ ____ pF ____ CPD Power dissipation pF 69 ____ ____ ____ capacitance (Note)

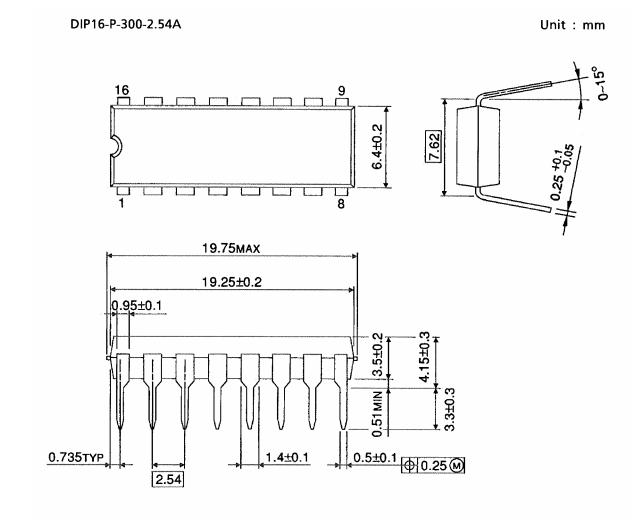
AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions



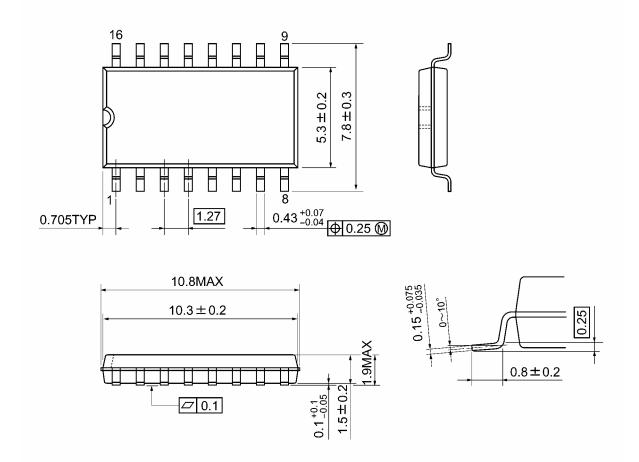
Weight: 1.00 g (typ.)



Package Dimensions

SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

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20070701-EN GENERAL

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